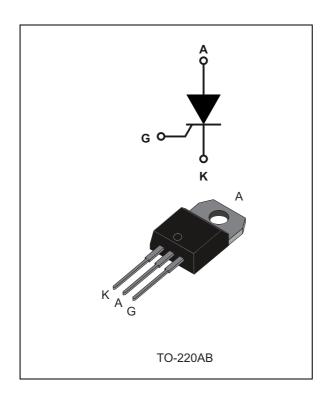
### TN2015H-6T



## High temperature 20 A SCRs

Datasheet - production data



### **Description**

Thanks to a junction temperature  $T_j$  up to 150 °C and a non-isolated TO-220 package, the TN2015H-6T offers high thermal performance up to 20 A rms.

The trade-off between the device's noise immunity (dV/dt = 750 V/ $\mu$ s), its gate triggering current (I<sub>GT</sub> = 15 mA) and its turn-on current rise (dI/dt = 100 A/ $\mu$ s) allows the design of robust and compact control circuits for voltage regulators in motorbikes and industrial drives, overvoltage crowbar protection, motor control circuits in power tools and kitchen appliances, and inrush current limiting circuits.

**Table 1. Device summary** 

Order code	Package	V <sub>DRM</sub> /V <sub>RRM</sub>	I <sub>GT</sub>
TN2015H-6T	TO-220AB	600 V	15 mA

### **Features**

- High junction temperature: T<sub>i</sub> = 150 °C
- High noise immunity dV/dt = 750 V/μs up to 150 °C
- Gate triggering current I<sub>GT</sub> = 15 mA
- Blocking voltage V<sub>DRM</sub>/V<sub>RRM</sub> = 600 V
- High turn on current rise dl/dt: 100 A/µs
- ECOPACK<sup>®</sup>2 compliant component

## **Applications**

- · Voltage regulator circuits for motorbikes
- · Inrush current limiting circuits
- · Motor control circuits and starters
- Light dimmers
- Solid state relays

Characteristics TN2015H-6T

# 1 Characteristics

**Table 2. Absolute ratings** 

Symbol	Parameter			Value	Unit	
I <sub>T(RMS)</sub>	On-state rms current (180° conduction a	T <sub>c</sub> = 132 °C	20	Α		
			T <sub>C</sub> = 132 °C	12.7		
I <sub>T(AV)</sub>	Average on-state current (180° conduction angle)		T <sub>c</sub> = 137 °C	10	Α	
			T <sub>c</sub> = 140 °C	8	1	
l	Non repetitive surge peak on-state curre	t = 8.3  ms	197	Α		
ITSM	(T <sub>j</sub> initial = 25 °C)		t = 10 ms	180	^	
l <sup>2</sup> t	$I^2$ t value for fusing ( $T_j$ initial = 25 °C)	$t_p = 10 \text{ ms}$	162	A <sup>2</sup> s		
dl/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$ , $t_r \le 100 \text{ ns}$ , $T_j = 25 \text{ °C}$		F = 60 Hz	100	A/µs	
V <sub>DRM</sub> , V <sub>RRM</sub>	Repetitive peak off-state voltage		600	V		
$I_{GM}$	Peak gate current $t_p = 20 \mu s$		T <sub>j</sub> = 150 °C	4	Α	
P <sub>G(AV)</sub>	Average gate power dissipation $T_j = 150 ^{\circ}\text{C}$		T <sub>j</sub> = 150 °C	1	V	
T <sub>stg</sub> T <sub>j</sub>	Storage junction temperature range Operating junction temperature range		- 40 to + 150 - 40 to + 150	°C		
T <sub>L</sub>	Maximum lead temperature for soldering during 10 s			260	ç	

Table 3. Electrical characteristics ( $T_j = 25$  °C, unless otherwise specified)

Symbol	Test conditions			Value	Unit
1	$V_D = 12 \text{ V}, R_L = 33 \Omega$		Тур.	6	mA
I <sub>GT</sub>			Max.	15	ША
$V_{GT}$	$V_D = 12 \text{ V}, R_L = 33 \Omega$		Max.	1.3	V
V <sub>GD</sub>	$V_D = V_{DRM}$ , $R_L = 3.3 \text{ k}\Omega$ $T_j = 150 \text{ °C}$		Min.	0.2	V
I <sub>H</sub>	I <sub>T</sub> = 500 mA, gate open		Max.	50	mA
ΙL	I <sub>G</sub> = 1.2 x I <sub>GT</sub>		Max.	60	mA
dV/dt	$V_D = 402 \text{ V, gate open}$ $T_j = 150 \text{ °C}$		Min.	750	V/µs
t <sub>gt</sub>	$I_T = 40 \text{ A}, V_D = 600 \text{ V}, I_G = 100 \text{ mA},$ $(dI_G/dt) \text{max} = 0.2 \text{ A/}\mu\text{s}$		Тур	1.9	μs
t <sub>q</sub>	$V_D = 402 \text{ V}, V_R = 25 \text{ V}, I_T = 20 \text{ A}, \\ (dI_G/dt) max = 30 \text{A}/\mu \text{s}, dV_D/dt = 50 \text{ V}/\mu \text{s} $ $T_j = 150 \text{ °C}$		Тур	70	μs

TN2015H-6T Characteristics

**Table 4. Static characteristics** 

Symbol	Test conditions			Value	Unit
$V_{TM}$	$I_{TM} = 40 \text{ A}, t_p = 380 \mu \text{s}$	T <sub>j</sub> = 25 °C	Max.	1.6	V
V <sub>t0</sub>	Threshold voltage	T <sub>j</sub> = 150 °C	Max.	0.82	V
R <sub>d</sub>	Dynamic resistance	T <sub>j</sub> = 150 °C	Max.	17.5	mΩ
I <sub>DRM,</sub>	$V_D = V_{DRM}, V_R = V_{RRM}$	T <sub>j</sub> = 25 °C	Max.	5	μΑ
I <sub>RRM</sub>		T <sub>j</sub> = 150 °C	iviax.	2	mA

Table 5. Thermal resistance

Symbol	Parameter	Value	Unit
R <sub>th(j-c)</sub>	Junction to case (AC)	1.0	°C/W
R <sub>th(j-a)</sub>	Junction to ambient (DC)	60	°C/W

Figure 1. Maximum power dissipation versus average on-state current

20 P(W) α = 180° DC. 18 α = 120° α = 90° 16 14  $\alpha = 30$ 12 10 8 6 4 2  $I_{\mathsf{T}(\mathsf{AV})}(\mathsf{A})$ 15 10

Figure 2. Average and DC on-state current versus case temperature

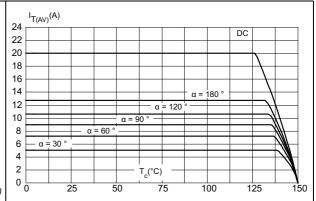
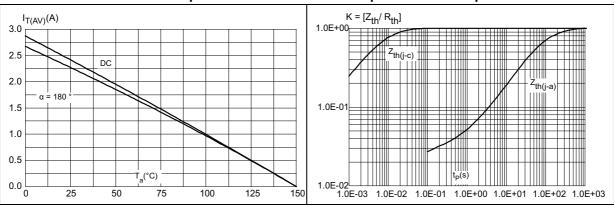


Figure 3. Average and DC on-state current versus ambient temperature

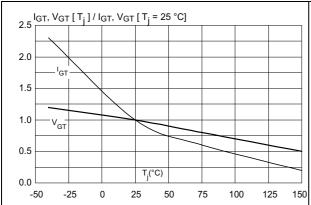
Figure 4. Relative variation of thermal impedance versus pulse duration



Characteristics TN2015H-6T

Figure 5. Relative variation of gate triggering current and gate voltage versus junction temperature (typical values)

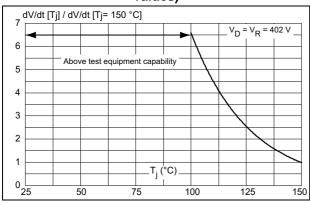
Figure 6. Relative variation of holding current and latching current versus junction temperature (typical values)



2.5 2.0 1.5 1.0 0.5 0.0 -50 -25 0 25 50 75 100 125 150

Figure 7. Relative variation of static dV/dt immunity versus junction temperature (typical values)

Figure 8. Surge peak on-state current versus number of cycles



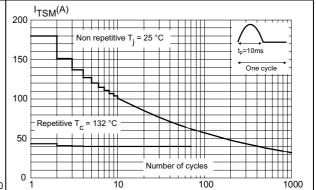
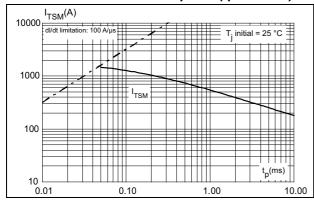
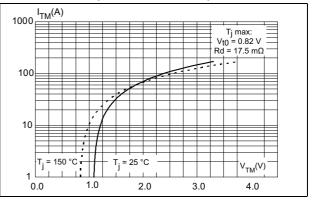


Figure 9. Non-repetitive surge peak on-state current for a sinusoidal pulse (tp < 10 ms)

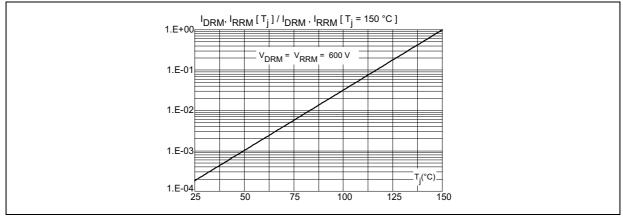
Figure 10. On-state characteristics (maximum values)





TN2015H-6T Characteristics

Figure 11. Relative variation of leakage current versus junction temperature (tp < 10 ms)



Package information TN2015H-6T

# 2 Package information

- Epoxy meets UL94, V0
- Lead-free package
- Halogen free molding compound
- Recommended torque: 0.4 to 0.6 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <a href="https://www.st.com">www.st.com</a>. ECOPACK<sup>®</sup> is an ST trademark.

B Ø I b2 F F I A A I C1

Figure 12. TO-220AB dimension definitions

TN2015H-6T Package information

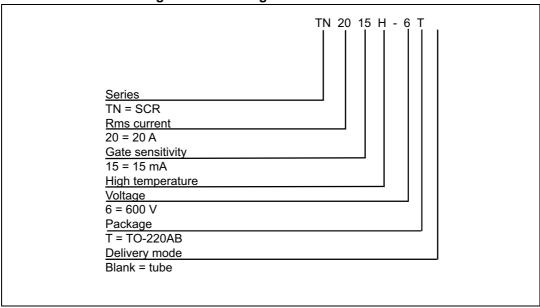
Table 6. TO-220AB dimension values

	Dimensions						
Ref.		Millimeters			Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.	
А	15.20		15.90	0.598		0.625	
a1		3.75			0.147		
a2	13.00		14.00	0.511		0.551	
В	10.00		10.40	0.393		0.409	
b1	0.61		0.88	0.024		0.034	
b2	1.23		1.32	0.048		0.051	
С	4.40		4.60	0.173		0.181	
c1	0.49		0.70	0.019		0.027	
c2	2.40		2.72	0.094		0.107	
е	2.40		2.70	0.094		0.106	
F	6.20		6.60	0.244		0.259	
ØI	3.75		3.85	0.147		0.151	
14	15.80	16.40	16.80	0.622	0.646	0.661	
L	2.65		2.95	0.104		0.116	
l2	1.14		1.70	0.044		0.066	
13	1.14		1.70	0.044		0.066	
М		2.60			0.102		

Ordering information TN2015H-6T

# 3 Ordering information

Figure 13. Ordering information scheme



**Table 7. Ordering information** 

Order code	Marking	Package	Weight	Base qty	Delivery mode
TN2015H-6T	TN2015H6	TO-220AB	2.3 g	50	Tube

# 4 Revision history

Table 8. Document revision history

Date	Revision	Changes
25-Feb-2015	1	Initial release.

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